

Description

The device has been especially designed to protect 2 new high voltage, as well as classical SLICs, against transient over-voltages.

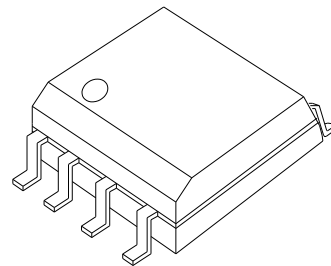
Positive over-voltages are clamped by 2 diodes. Negative surges are suppressed by 2 thyristors, their breakdown voltage being referenced to $-V_{BAT}$ through the gate.

The component presents a very low gate triggering current (I_{GT}) in order to reduce the current consumption on printed circuit board during the firing phase.

The device is not subject to ageing and provide a fail safe mode in short circuit for a better protection. TS61089BX-H is used to help equipment to meet various standards such as UL1950, IEC950/CSA C22.2, UL1459 and FCC part68.

Features

- Dual line programmable transient voltage suppressor
- Wide negative firing voltage range:
 $V_{MGL} = -167V$
- Low dynamic switching voltages: V_{FP} and V_{DGL}
- Low gate triggering current: $I_{GT} = 5 \text{ mA max}$
- Peak pulse current: $I_{PP} = 100A (10/1000 \text{ s})$
- Holding current: $I_H > 150 \text{ mA}$
- Solid-state silicon technology
- Meets MSL 3 Requirements
- ROHS compliant



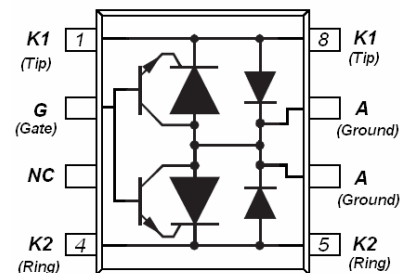
Device package type SOP-8

Main applications

- T-1/E-1, ISDN, and xDSL transmission equipment
- Telecommunications infrastructure
- PBX's and other switches
- Set-top box
- VoIP

Protection solution to meet

- TIA-968-A/TIA-968-B
- ITU K.20/21 Enhanced Level*/Basic Level
- GR 1089 Inter-building*/Intra-building
- IEC 61000-4-5
- YD/T 1082
- YD/T 993
- YD/T 950



Ordering Information

Device	Qty per Reel	Reel Size
TS61089BX-H	3000	13 Inch

Maximum ratings (Tamb=25°C Unless Otherwise Specified)			
Parameter	Symbol	Value	Unit
Repetitive peak off-state voltage, $V_{GK}=0$	V_{DRM}	-170	V
Repetitive peak gate-cathode voltage, $V_{KA}=0$	V_{GKRM}	-170	V
Non-repetitive peak on-state current 10/1000 us (Telcordia(Bellcore)Gr-1089-CORE.Issue 2.February 1999,Section4) 5/320 us (ITU-T K.20, K.21& K.45, K.44 open-circuit voltage wave shape 10/700us)	I_{PPSM}	100	A
		150	
Non-repetitive peak on-state current. $V_{GG}=-75V$ 50Hz to 60Hz 10ms 1 s	I_{TSM}	8	A
		3.5	
Lead Soldering Temperature	T_L	260 (10 sec.)	°C
Operating Temperature Range	T_J	-40 ~ 85	°C
Storage Temperature Range	T_{STG}	-55 ~ 150	°C
Lead Solder Temperature – Maximum (10 Second Duration)	T_L	260	°C
Junction To ambient	$R_{\theta JA}$	170	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

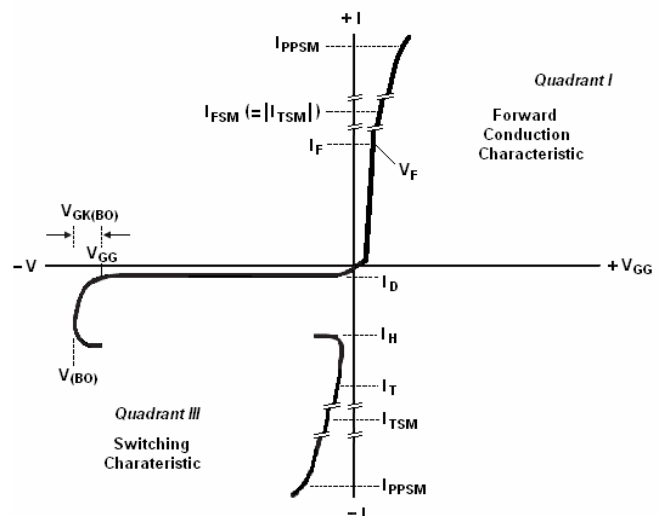
*Other voltages may be available upon request.

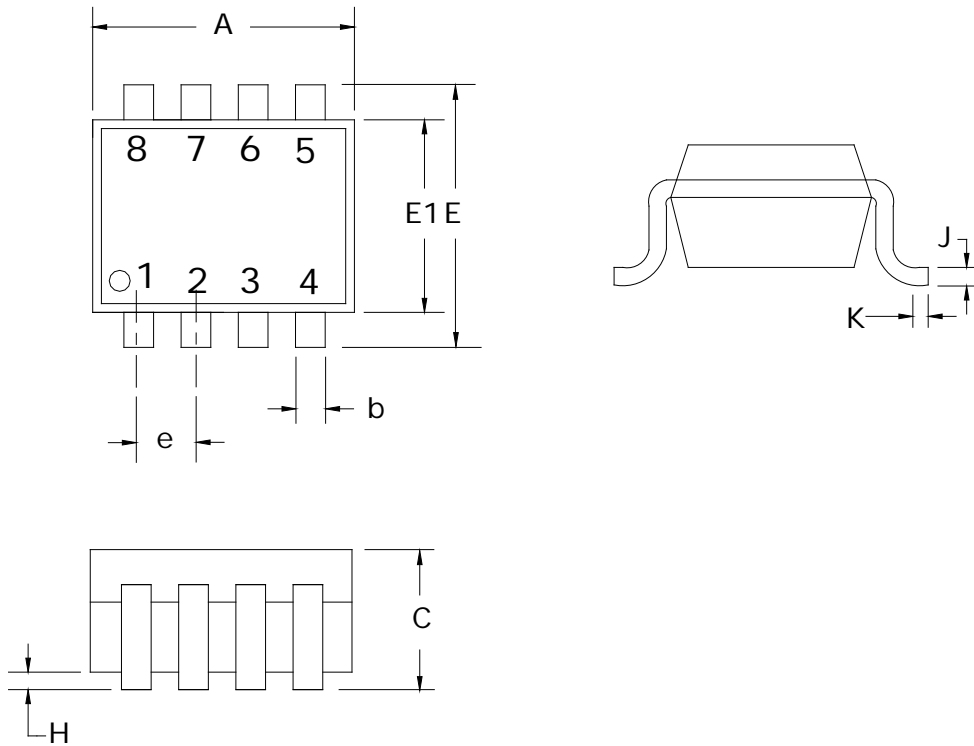
1. Nonrepetitive current pulse, per Figure 1.

Electrical characteristics (T_{amb}=25°C Unless Otherwise Specified)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
I _D	Off-state current	V _D =V _{DRM} , V _{GK} =0			-5	μA
		T _J =25 °C				
V _(BO)	Breakover voltage	2/10us, I _{PP} = -56A, R _S = 45Ω, V _{GG} = -48V, C _G = 220nF		-57		V
		2/10us, I _{PP} = -100A, R _S = 50Ω, V _{GG} = -48V, C _G = 220nF		-60		
		1.2/50us, I _{PP} = -53A, R _S = 47Ω, V _{GG} = -48V, C _G = 220nF		-60		
		1.2/50us, I _{PP} = -96A, R _S = 52Ω, V _{GG} = -48V, C _G = 220nF		-64		
V _{GK(BO)}	Gate-cathode impulse Breakover voltage	2/10us, I _{PP} = -56A, R _S = 45Ω, V _{GG} = -48V, C _G = 220nF		9		V
		2/10us, I _{PP} = -100A, R _S = 50Ω, V _{GG} = -48V, C _G = 220nF		12		
		1.2/50us, I _{PP} = -53A, R _S = 47Ω, V _{GG} = -48V, C _G = 220nF		12		
		1.2/50us, I _{PP} = -96A, R _S = 52Ω, V _{GG} = -48V, C _G = 220nF		16		
V _F	Forward voltage	I _F = 5 A, T _W = 200 us			3	V
V _{FRM}	Peak forward recovery voltage	2/10us, I _{PP} = -56A, R _S = 45Ω, V _{GG} = -48V, C _G = 220nF		6		V
		2/10us, I _{PP} = -100A, R _S = 50Ω, V _{GG} = -48V, C _G = 220nF		8		
		1.2/50us, I _{PP} = -53A, R _S = 47Ω, V _{GG} = -48V, C _G = 220nF		8		
		1.2/50us, I _{PP} = -96A, R _S = 52Ω, V _{GG} = -48V, C _G = 220nF		12		
I _H	Holding current	I _T = -1 A, di/dt = 1A/ms, V _{GG} = -48 V	-150			mA
I _{GKS}	Gate reverse current	V _{GG} = V _{GK} = V _{GKRM} , V _{KA} = 0			-5	μA
		T _J =25 °C				
		T _J =85 °C			-50	μA
I _{GT}	Gate trigger current	I _T = -3 A, t _{p(g)} ≥ 20 us, V _{GG} = -48V			5	mA
V _{GT}	Gate-cathode trigger voltage	I _T = -3 A, t _{p(g)} ≥ 20 us, V _{GG} = -48V			2.5	V
Q _{GS}	Gate switching charge	1.2/50us, I _{PP} = -53A, R _S = 47Ω, V _{GG} = -48V, C _G = 220nF		0.1		uC
C _{KA}	Cathode-anode off-State capacitance	F=1 MHz, V _d =1V, I _G =0	V _D = -3 V		100	pF
			V _D = -48 V		50	pF

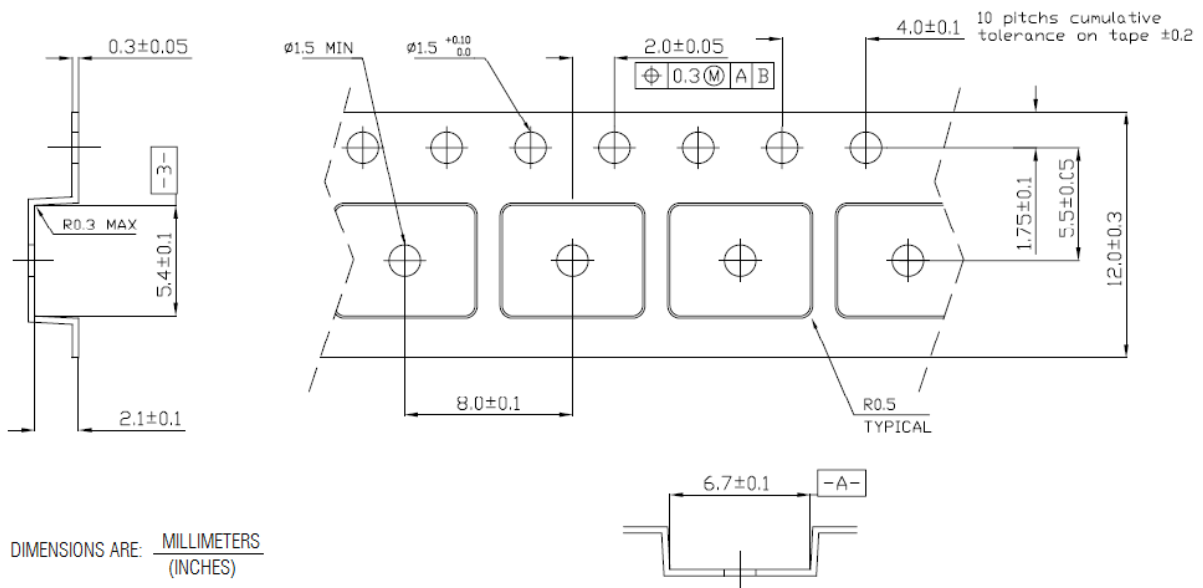
Symbol	Parameter
I _D	Off-state current
I _H	Holding current
V _(BO)	Breakover voltage
V _F	Forward voltage
V _{FRM}	Peak forward recovery voltage
V _{GK(BO)}	Gate-cathode impulse breakover voltage
I _{GKS}	Gate reverse current
I _{GT}	Gate trigger current
V _{GT}	Gate-cathode trigger voltage
C _{KA}	Cathode-anode off-state capacitance



Package information
SOP-8


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	4.80	5.00	0.189	0.197
E	6.00(BSC)		0.236(BSC)	
E1	3.80	4.00	0.150	0.157
b	0.35	0.49	0.014	0.019
C	1.35	1.79	0.054	0.068
J	0.18	0.25	0.007	0.009
e	1.27(BSC)		0.05(BSC)	
K	0.40	1.25	0.016	0.049
H	0.10	0.25	0.004	0.008

Tape and Reel Specification



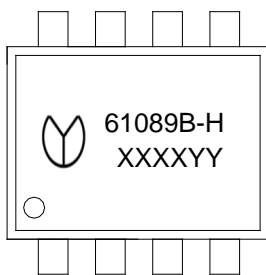
NOTES: A. Taped devices are supplied on a reel of the following dimensions:

$$\text{Reel diameter: } \frac{328 \pm 1.0}{16.8 \pm 0.5a}$$

$$\text{Reel hub diameter: } \frac{100 \pm 1.0}{12.8 \pm 0.5a}$$

B. 2500 devices are on a reel.

Marking Codes



Note:

- (1) "61089B-H" is part number, fixed.
- (2) "XXXX" is the last 4 characters of the wafer's Lot No.,
"YY" is the internal code.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [ESD Suppressors / TVS Diodes](#) category:

Click to view products by [Shenzhen JingYang](#) manufacturer:

Other Similar products are found below :

[60KS200C](#) [D18V0L1B2LP-7B](#) [D5V0F4U5P5-7](#) [NTE4902](#) [P4KE27CA](#) [P6KE11CA](#) [P6KE8.2A](#) [SA60CA](#) [SA64CA](#) [SMBJ12CATR](#)
[SMBJ33CATR](#) [SMBJ6.5A](#) [SMBJ8.0A](#) [ESD101-B1-02ELS](#) [E6327](#) [ESD112-B1-02EL](#) [E6327](#) [ESD7451N2T5G](#) [19180-510](#) [CPDT-5V0USP-](#)
[HF](#) [3.0SMCJ33CA-F](#) [3.0SMCJ36A-F](#) [HSPC16701B02TP](#) [JANTX1N6126A](#) [D3V3Q1B2DLP3-7](#) [D55V0M1B2WS-7](#) [SCM1293A-04SO](#)
[ESD200-B1-CSP0201](#) [E6327](#) [SM12-7](#) [CEN955](#) [W/DATA](#) [VESD12A1A-HD1-GS08](#) [CPDQC5V0-HF](#) [D1213A-01LP4-7B](#) [ESD101-B1-02EL](#)
[E6327](#) [AOZ8808DI-03](#) [5KP15A](#) [5KP48A](#) [5KP90A](#) [ESD3V3D7-TP](#) [15KPA36A-LF](#) [P4KE56CA](#) [P4KE68A](#) [P4KE91CATR](#) [P6KE120A](#)
[P6KE13CA](#) [P6KE43CA](#) [P6KE6.8CA](#) [P6KE8.2](#) [P6SMBJ20CA](#) [JANTX1N6072A](#) [SR2835ESKG](#) [SA90CA](#)